

November 2013

FDPF16N50 / FDPF16N50T N-Channel UniFET™ MOSFET 500 V, 16 A, 380 mΩ

Features

- $R_{DS(on)}$ = 380 $m\Omega$ (Max.) @ V_{GS} = 10 V, I_D = 8 A
- Low Gate Charge (Typ. 32 nC)
- · Low Crss (Typ. 20 pF)
- 100% Avalanche Tested

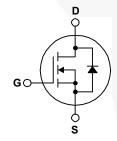
Applications

- LCD/LED/PDP TV
- Lighting
- · Uninterruptible Power Supply

Description

UniFET™ MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





Absolute Maximum Ratings TC = 25°C unless otherwise noted.

Symbol	Parameter		FDPF16N50 FDPF16N50T	Unit		
V _{DSS}	V _{DSS} Drain-Source Voltage			500	V	
I _D	Drain Current	- Continuous (T _C = 25°C) - Continuous (T _C = 100°C)		16* 9.6*	A A	
I _{DM}	Drain Current	- Pulsed	(Note 1)	64*	А	
V _{GSS}	Gate-Source voltage			±30	V	
E _{AS}	Single Pulsed Avalanche Energy (Note 2		(Note 2)	780	mJ	
I _{AR}	Avalanche Current (Note 1		(Note 1)	16	Α	
E _{AR}	Repetitive Avalanche Energy (Note 1		(Note 1)	20	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		(Note 3)	4.5	V/ns	
P _D	Power Dissipation (T _C = 25°C) - Derate above 25°C			38.5 0.3	W W/°C	
T _{J,} T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
T _L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C	

^{*} Drain current limited by maximum junction temperature.

Thermal Characteristics

Symbol	Parameter	FDPF16N50 FDPF16N50T	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	3.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDPF16N50	FDPF16N50	TO-220F	Tube	N/A	N/A	50 units
FDPF16N50T	FDPF16N50T	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics T_C = 25°C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max	Unit
Off Charac	teristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$				V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250μA, Referenced to 25°C		0.5		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 500V, V _{GS} = 0V V _{DS} = 400V, T _C = 125°C			1 10	μ Α μ Α
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30V, V _{DS} = 0V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30V, V _{DS} = 0V			-100	nA
On Charac	teristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10V, I _D = 8A	-	0.31	0.38	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 40V, I_{D} = 8A$		23		S
Dynamic C	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$		1495	1945	pF
C _{oss}	Output Capacitance	f = 1.0MHz		235	310	pF
C _{rss}	Reverse Transfer Capacitance			20	30	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 250V, I _D = 16A		40	90	ns
t _r	Turn-On Rise Time	$R_G = 25\Omega$		150	310	ns
t _{d(off)}	Turn-Off Delay Time			65	140	ns
t _f	Turn-Off Fall Time	(Note 4)	/	80	170	ns
Qg	Total Gate Charge	V _{DS} = 400V, I _D = 16A	/	32	45	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10V		8.5		nC
Q _{gd}	Gate-Drain Charge	(Note 4)	A	14		nC
Drain-Sour	rce Diode Characteristics and Maximur	m Ratings				ı
I _S	Maximum Continuous Drain-Source Diode Forward Current				9.2	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				37	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0V, I _S = 16A			1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0V, I _S = 16A		490		ns
Q _{rr}	Reverse Recovery Charge	dI _F /dt =100A/μs	/	5.0		μС

NOTES:

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2. L = 5.5 mH, I $_{AS}$ = 16 A, V $_{DD}$ = 50 V, R $_{G}$ = 25 Ω , starting T $_{J}$ = 25°C.
- 3. I $_{SD} \leq$ 16 A, di/dt \leq 200 A/µs, V $_{DD} \leq$ BV $_{DSS}$, starting T $_{J}$ = 25°C.
- 4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

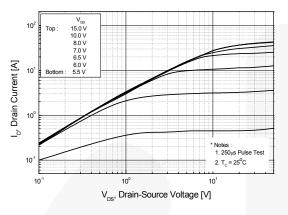


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

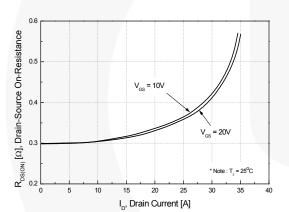


Figure 5. Capacitance Characteristics

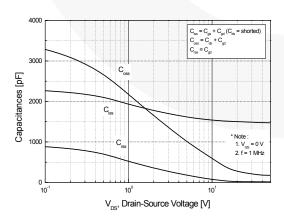


Figure 2. Transfer Characteristics

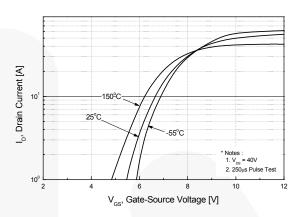


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperatue

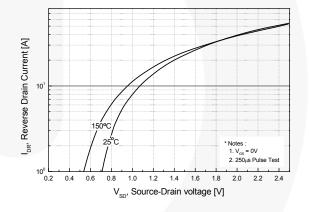
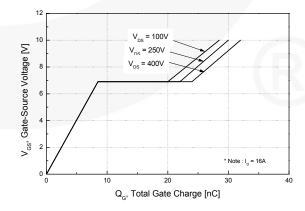


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

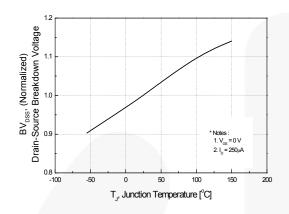


Figure 8. On-Resistance Variation vs. Temperature

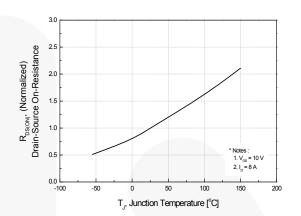


Figure 9. Maximum Safe Operating Area

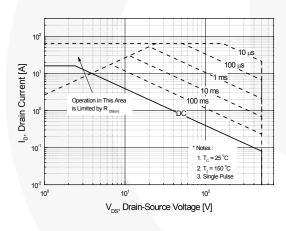


Figure 10. Maximum Drain Current vs. Case Temperature

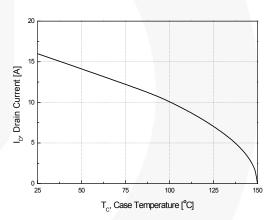
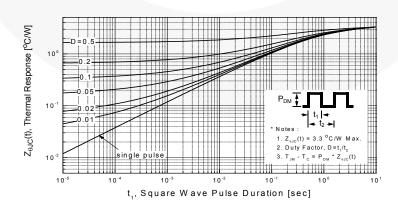


Figure 11. Transient Thermal Response Curve



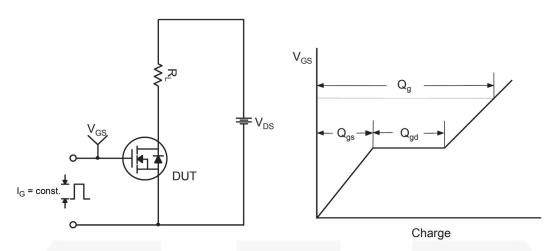


Figure 12. Gate Charge Test Circuit & Waveform

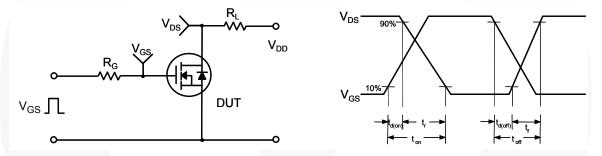


Figure 13. Resistive Switching Test Circuit & Waveforms

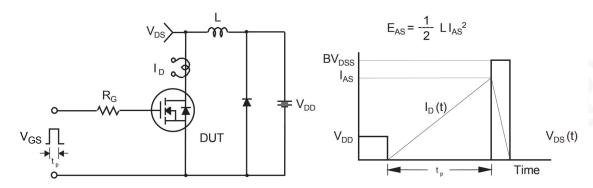


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

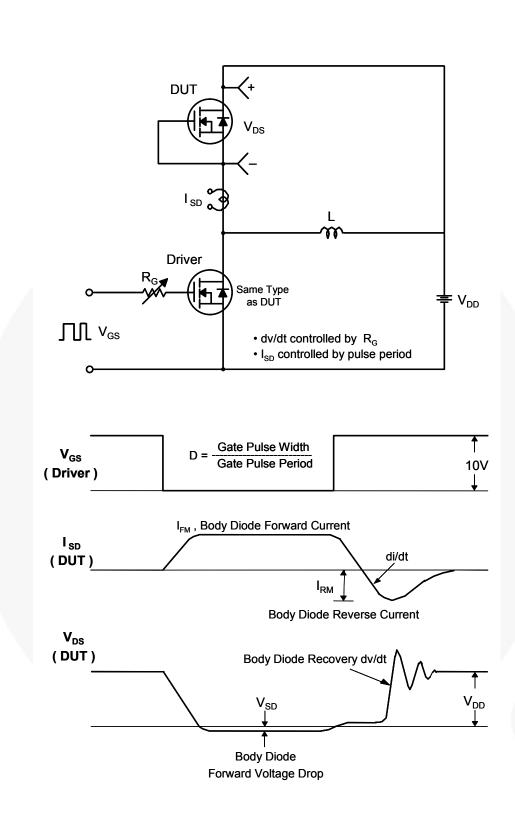


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

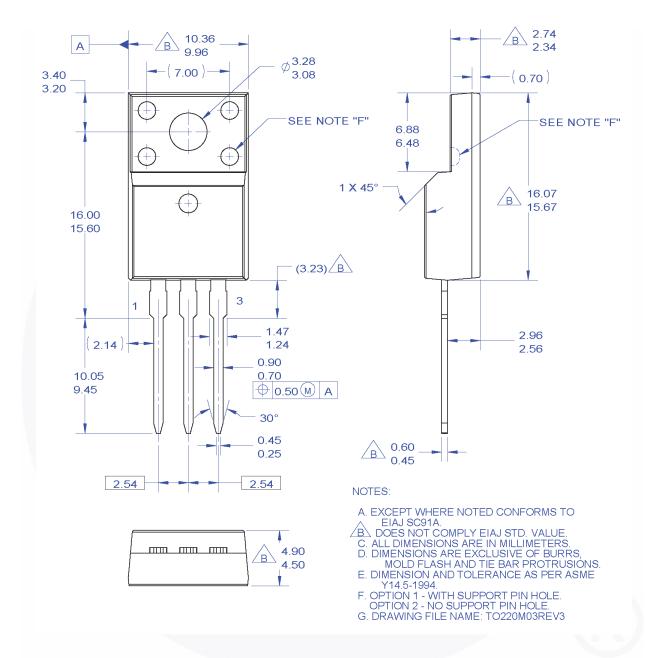


Figure 17. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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